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September 2016

# GreenBridge<sup>™</sup> 2 Series of High-Efficiency Bridge Rectifiers

#### Features

- Low Power Loss GreenBridge<sup>TM</sup> Replaces Diode Bridge
- Self Driving Circuitry for MOSFETs
- Low r<sub>DS(on)</sub> 80V Rated MOSFETs
- Maximizing Available Power and Voltage
- Eliminating Thermal Design Problems
- IEEE802.3at Compatible
  - Meet Detection and Classification Requirement
  - Work with 2 and 4-pair Architecture
  - Small Backfeed Voltage
- Compact MLP 4.5x5 Package

#### Applications

- Power over Ethernet (PoE) Power Device (PD)
  - IP Phones
  - Network Cameras
  - Wireless Access Points
  - Thin Clients
  - Microcell
  - Femtocell

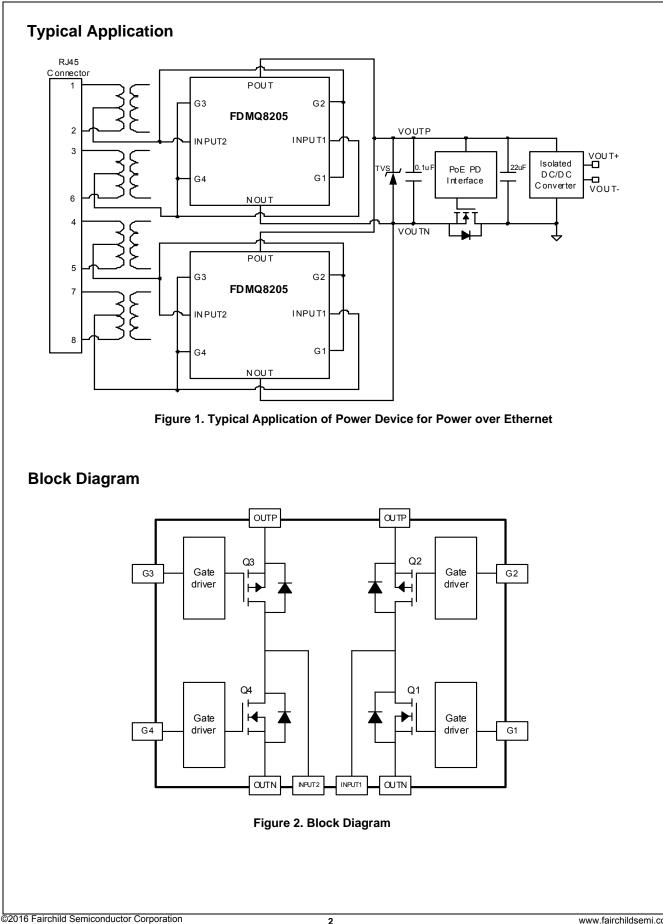
#### **General Description**

FDMQ8205 is GreenBridge<sup>TM</sup>2 series of quad MOSFETs for a bridge application so that the input will be insensitive to the polarity of a power source coupled to the device. Many known bridge rectifier circuits can be configured using typical diodes. The conventional diode bridge has relatively high power loss that is undesirable in many applications. Especially, Power over Ethernet (PoE) Power Device (PD) application requires high-efficiency bridges because it should be operated with the limited power delivered from Power Source Equipment (PSE) which is classified by IEEE802.3at. FDMQ8205 is configured with low  $r_{DS(on)}$  dual P-ch MOSFETs and N-ch MOSFETs so that it can reduce the power loss caused by the voltage drop, compared to the conventional diode bridge. FDMQ8205 enables the application to maximize the available power and voltage and to eliminate the thermal design problems in PoE PD applications.

FDMQ8205 GreenBridge<sup>TM</sup>2 is compatible with IEEE802.3at PoE standard by not compromising detection and classification requirement as well as small backfeed voltage.

#### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMQ8205	FDMQ8205	MLP4.5x5	13 "	12 mm	3000 units



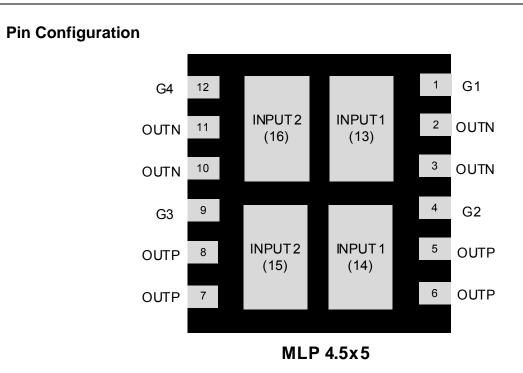


Figure 3. Pin Assignment (Bottom View)

# **Pin Descriptions**

Pin Number	Name	Description
1	G1	Gate of Q1 N-ch MOSFET
4	G2	Gate of Q2 P-ch MOSFET
9	G3	Gate of Q3 P-ch MOSFET
12	G4	Gate of Q4 N-ch MOSFET
13,14	INPUT1	Input1 of GreenBridge <sup>TM</sup>
15,16	INPUT2	Input2 of GreenBridge <sup>TM</sup>
2,3,11,10	OUTN	Negative Output of GreenBridge <sup>TM</sup>
5,6,7,8	OUTP	Positive Output of GreenBridge <sup>TM</sup>

Notes:

1. Show the feature that provides orientation or pin 1 location.

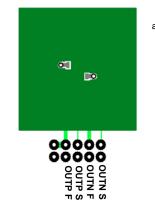
# **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

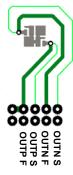
			Min.	Max.	Units
INPUT1, INPUT2 to OUTN				80	V
OUTP to IN	OUTP to INPUT1, INPUT2			80	V
INPUT1	to INPUT2			80	V
INPUT2	to INPUT1			80	V
OUTP	to OUTN			80	V
G1, G2, G3, G4 to OUTN				70	V
OUTP to G1, G2, G3, G4				70	V
V <sub>G_TRANSIENT</sub>	Transient Gate Voltage, Pulse W Duty Cycle < 0.003	• •		100	V
Continuous I <sub>INPLIT</sub> (GreenBridge <sup>TM</sup> Current,	T <sub>A</sub> = 25 °C	(Note 2a)		3.0	А
Q1+Q3 or Q2+Q4)	T <sub>A</sub> = 25 °C	(Note 2b)		1.7	А
Pulsed I <sub>INPUT</sub> (Q1+Q3 or Q2+Q4)	Pulse Width < 300 µs, Duty Cycle	e < 2% (Note 3)		58	Α
P (Power Dissinction 01) 02 or 02) 01)	T <sub>A</sub> = 25 °C	(Note 2a)		2.5	W
P <sub>D</sub> (Power Dissipation, Q1+Q3 or Q2+Q4)	T <sub>A</sub> = 25 °C	(Note 2b)		0.78	W
Max Junction Temperature				150	°C

#### Notes :

2.  $R_{\theta JA}$  is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a. 50 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper, the board designed Q1+Q3 or Q2+Q4.



b. 160 °C/W when mounted on a minimum pad of 2 oz copper, the board designed Q1+Q3 or Q2+Q4.

3. Pulse Id measured at td <= 300µs, refer to SOA graph for more details.

### **Thermal Characteristics**

Symbol	Parameter		Min.	Тур.	Max.	Units
$R_{\thetaJC}$	Thermal Resistance, Junction to Case			5.1		
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 2a)		50		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 2b)		160		

### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Conditions	Min.	Max.	Units
V <sub>INPUT</sub>	Input Voltage of Bridge	INPUT1 to INPUT2 or INPUT2 to INPUT1		57	V
V <sub>G</sub>	Gate Voltage of MOSFETs	G1, G4 to OUTN G2, G3 to OUTP		57	V
I <sub>INPUT</sub>	Input Current of Bridge	Bridge Current through Q2 and Q4 or (Q3 and Q1)		1.7	А
	Ambient Operation Temperature (T <sub>A</sub> )			85	°C
	Junction Operating Temperature (T <sub>J</sub> ) (Note 5)			125	°C

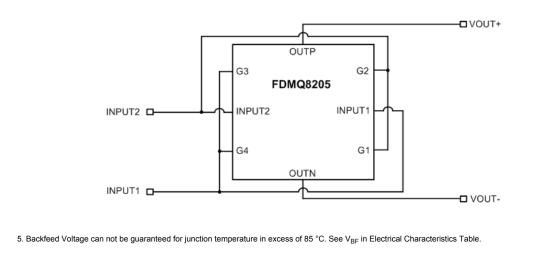
### **Electrical Characteristics**

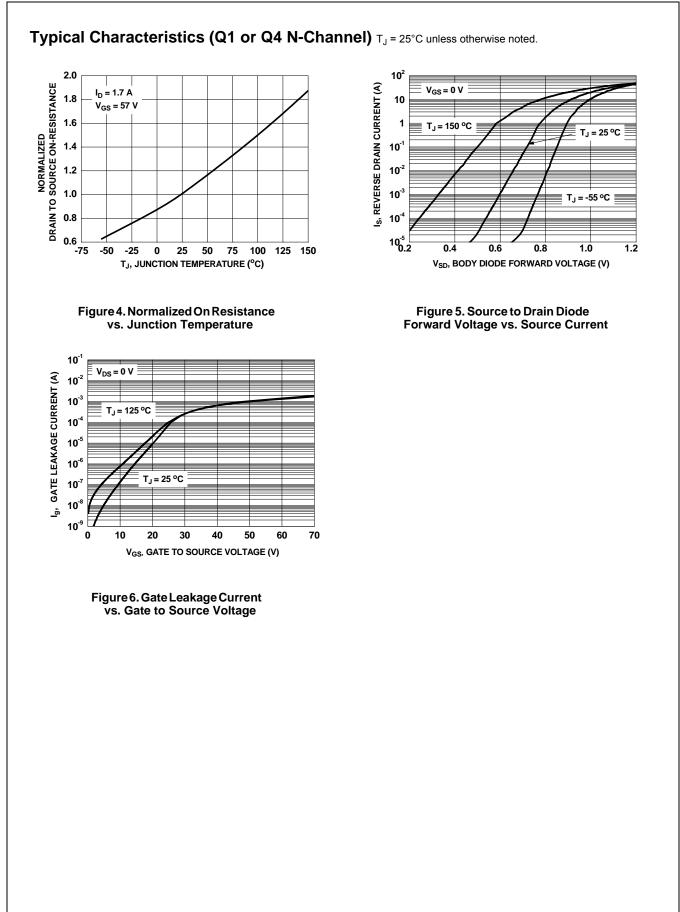
Unless otherwise noted:  $T_J = 25$  °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V <sub>INPUT</sub>	Input Voltage of Bridge	At INPUT1 to INPUT2 or INPUT2 to INPUT1			57	V
V <sub>G</sub>	Gate Voltage of MOSFETs	At G1, G4 to OUTN and G2, G3 to OUTP			57	V
IQ	Quiescent Current	Detection Mode 1.5 V $<$ V <sub>INPUT</sub> =V <sub>G</sub> $<$ 10.1V (Note 4)			5	μA
					400	μA
		Power On Mode Maximum $V_{INPUT}=V_G=57 V$ (Note 4)			3.2	mA
V <sub>TURN_ON</sub>	Turn-On Voltage of MOSFETs	Turn-On of MOSFETs while $V_G$ Increases (Note 4)	32		36	V
I <sub>LEAKAGE</sub>	Turn-Off Leakage Current	$V_{OUTP}$ =57 V, $V_{OUTN}$ =0 V T <sub>J</sub> = -40 °C to 85 °C (Note 4)			700	μA
$V_{BF}$	Backfeed Voltage	$V_{OUTP}$ =57 V, $V_{OUTN}$ =0 V, 100 kOhm between INPUT1 and INPUT2 $T_{J}$ = -40 °C to 85 °C (Note 4)			2.7	v
	N-ch MOSFET	V <sub>G</sub> =42 V, I <sub>INPUT</sub> =1.5 A, T <sub>A</sub> =25 °C		35	51	mΩ
		V <sub>G</sub> =48 V, I <sub>INPUT</sub> =1.5 A, T <sub>A</sub> =25 °C		29	44	mΩ
-		V <sub>G</sub> =57 V, I <sub>INPUT</sub> =1.5 A, T <sub>A</sub> =25 °C		26	37	mΩ
r <sub>DS(on)</sub>	P-ch MOSFET	V <sub>G</sub> = -42 V, I <sub>INPUT</sub> = -1.5 A, T <sub>A</sub> =25 °C		95	147	mΩ
		V <sub>G</sub> = -48 V, I <sub>INPUT</sub> = -1.5 A, T <sub>A</sub> =25 °C		83	125	mΩ
		V <sub>G</sub> = -57 V, I <sub>INPUT</sub> = -1.5 A, T <sub>A</sub> =25 °C		76	107	mΩ

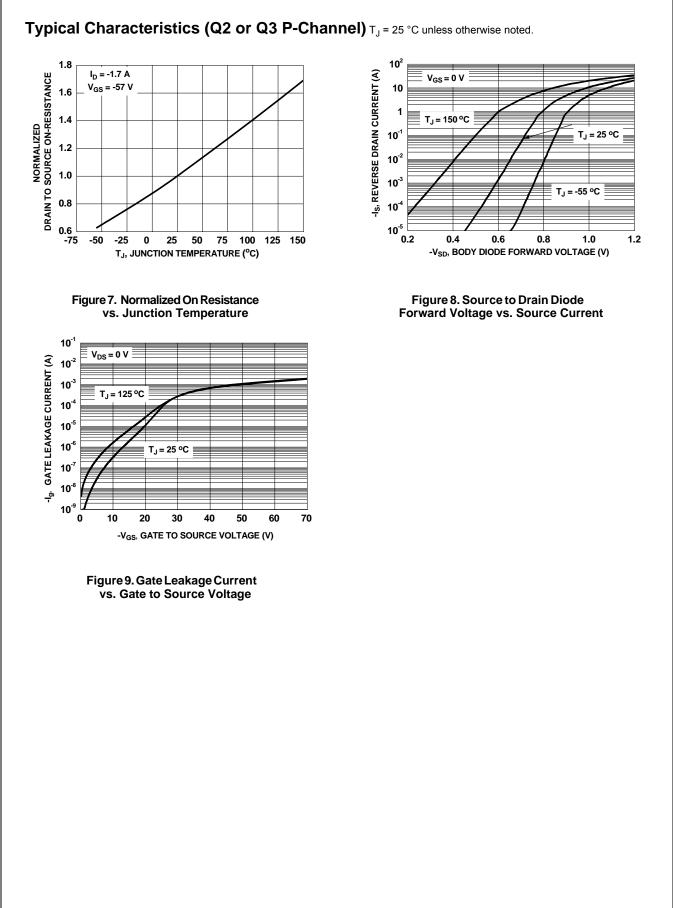
#### Notes:

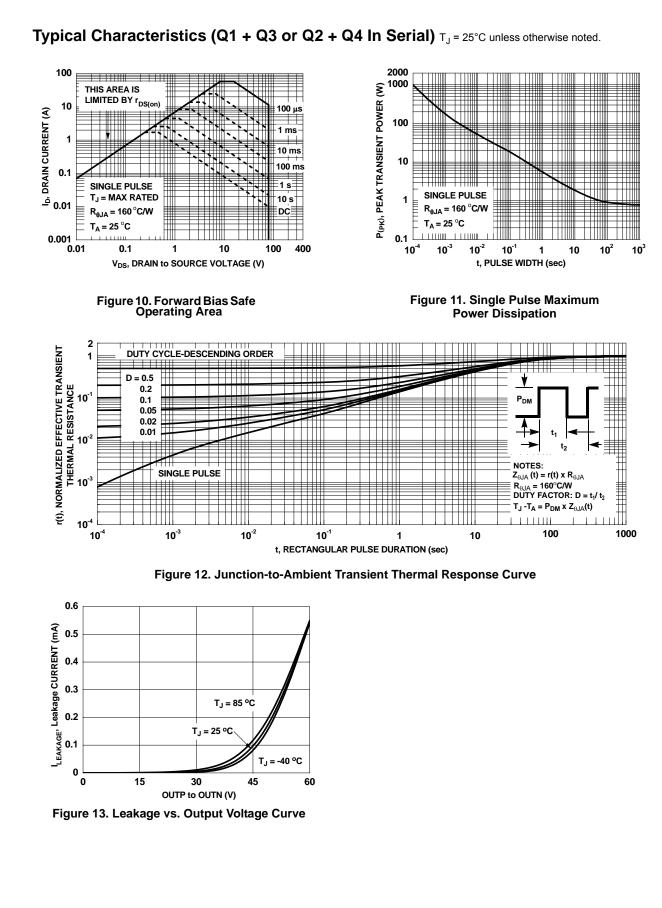
4. INPUT1 is connected to G3 and G4 and also INPUT2 is connected to G1 and G2 like below.

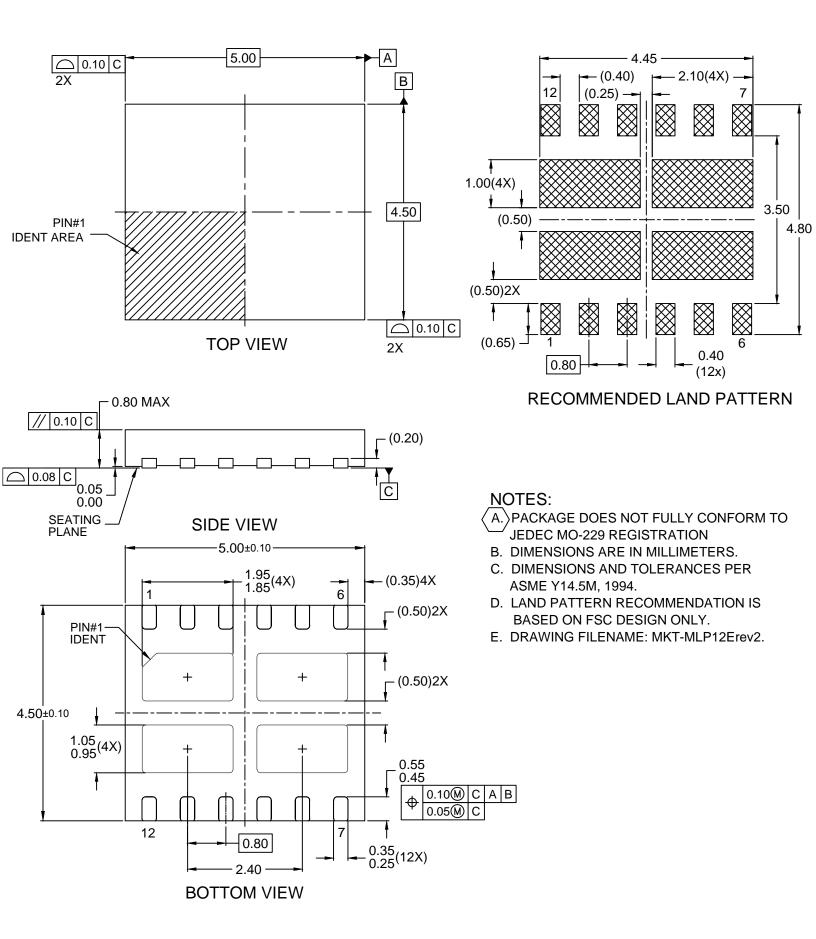




FDMQ8205 - GreenBridge<sup>TM</sup>2 Series of High-Efficiency Bridge Rectifiers







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